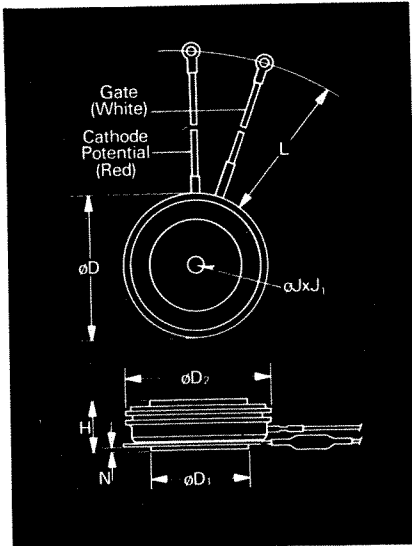


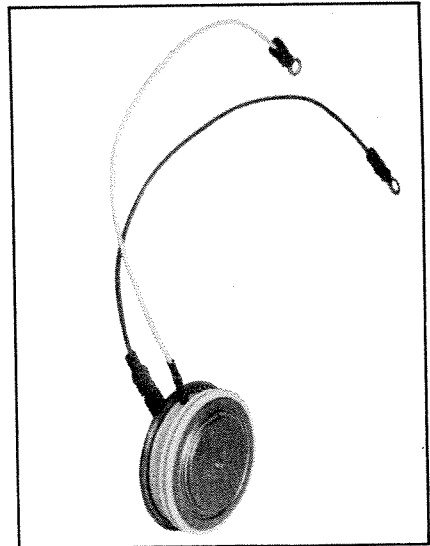
# Fast Switching SCR T7SH\_45

450A Avg.  
(700 RMS)  
Up to 1400 Volts  
25-50  $\mu$ s



Symbol	Inches		Millimeters	
	Min.	Max.	Min.	Max.
$\phi D$	1.850	1.900	45.72	48.26
$\phi D_1$	1.140	1.180	28.96	29.97
$\phi D_2$	1.760	1.850	44.70	46.99
H	.545	.605	13.84	15.37
$\phi J$	.135	.145	3.43	3.68
$J_1$	.072	.082	1.83	2.08
L	7.75	8.50	196.85	215.90
N	.025		.64	

Creep Distance—.41 in. min. (10.41 mm).  
Strike Distance—.35 in. min. (8.89 mm).  
Finish-Nickel Plate.  
Approx. Weight—4 oz. (113 g.)  
1. Dimension "H" is a clamped dimension.



### T7S Outline

- Features:**
- Interdigitated, di/namic Gate structure
  - Hard Commutation Turn-Off
  - Forward Blocking Capabilities to 1200 Volts
  - Low Switching Losses at High Frequency
  - Soft Commutation (Feedback Diode) Testing Available
  - High di/dt with softgate control

- Applications:**
- Induction Heating
  - Transportation
  - Inverters
  - Crowbars
  - Cycloconverters

### Ordering Information

Type	Voltage		Current		Turn-off		Gate current		Leads	
	V <sub>DRM</sub> and V <sub>RRM</sub> (V)	Code	I <sub>T(av)</sub> (A)	Code	t <sub>q</sub> usec	Code	I <sub>GT</sub> (ma)	Code	Case	Code
T7SH	100	01	450	45	25	B	150	4	T7S	DN
	200	02								
	300	03								
	400	04								
	500	05								
	600	06								
	700	07								
	800	08								
	900	09								
	1000	10								
	1100	11								
	1200	12								
	1400	14								

### Example

Obtain optimum device performance for your application by selecting proper Order Code.

Type T7SH rated at 450 A average with V<sub>DRM</sub> = 1000V, I<sub>GT</sub> = 150 ma, t<sub>q</sub> = 40  $\mu$ sec max. and leads—order as:

Type	Voltage	Current	Turn Off	Gate Current	Leads
T 7 S H	1 0	4 5	4	4	D N

FAST SWITCHING THYRISTORS

**450A Avg.  
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**Fast Switching  
SCR  
T7SH\_45**

**Voltage** ①

**Blocking State Maximums** ( $T_J = 125^\circ\text{C}$ )

Repetitive peak forward blocking voltage, V	$V_{DRM}$
Repetitive peak reverse voltage, V	$V_{RRM}$
Non-repetitive transient peak reverse voltage, $t \leq 5.0$ msec, V	$V_{RSM}$
Forward leakage current, mA peak	$I_{DRM}$
Reverse leakage current, mA peak	$I_{RRM}$

Symbol

100	200	300	400	500	600	700	800	900	1000	1100	1200	1400
100	200	300	400	500	600	700	800	900	1000	1100	1200	1400
200	300	400	500	600	700	800	900	1000	1100	1200	1300	1500

← 35 ————— →  
← 35 ————— →

**Current**

**Conducting State Maximums**  
( $T_J = 125^\circ\text{C}$ )

RMS forward current, A	$I_T(\text{rms})$
Ave. forward current, A	$I_T(\text{av})$
One-half cycle surge current ②, A	$I_{TSM}$
3 cycle surge current ③, A	$I_{TSM}$
10 cycle surge current ④, A	$I_{TSM}$
$I^2t$ for fusing (for times $\geq 8.3$ ms) A <sup>2</sup> sec.	$I^2t$
Forward voltage drop at $I_{TM} = 1500\text{A}$ and $T_J = 25^\circ\text{C}$ , V	$V_{TM}$
Min. repetitive $di/dt$ ①④⑤ A/ $\mu$ sec	$di/dt$

**T7SH\_45**

700
450
8500
6125
5290
301,000
2.0
600

**Switching**

( $T_J = 25^\circ\text{C}$ )

Max. turn-off time,  $I_T = 1000\text{A}$ ,  $T_J = 125^\circ\text{C}$   
 $t_p = 100$   $\mu$ sec,  $di/dt = 50$   
 A/ $\mu$ sec., reappplied  $dv/dt =$   
 $200\text{V}/\mu$ sec. linear to  $0.8 V_{DRM}$ ,  $\mu$ sec. ④⑤

Typ. delay time,  $I_{TM} = 1000\text{A}$   
 $T_D = .8 V_{DRM}$ ,  $\mu$ sec

Min. critical  $dv/dt$  exponential to  $.8$   
 $V_{DRM}$ ,  $T_J = 125^\circ\text{C}$ , V/ $\mu$ sec ①④

Min.  $di/dt$ , non-repetitive, A/ $\mu$ sec ①④⑤

Symbol	
$t_q$	25 to 50
$t_d$	.5
$dv/dt$	300
$di/dt$	1200

**Gate**

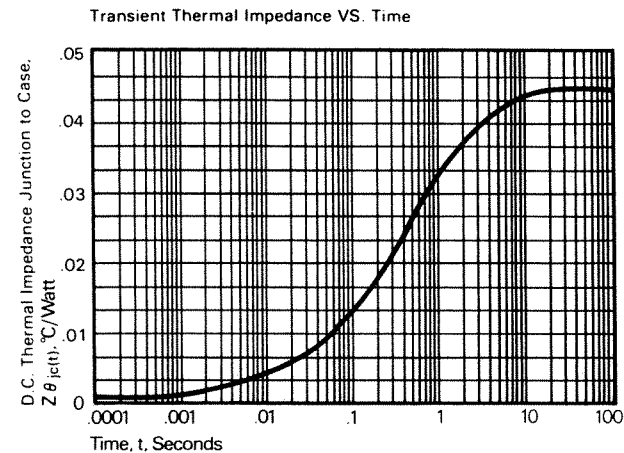
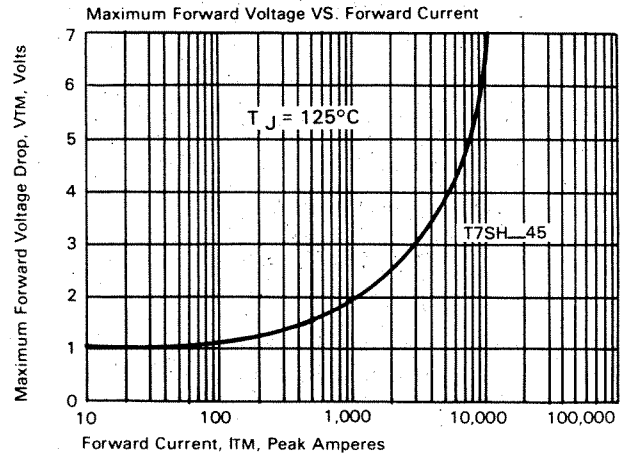
**Maximum Parameters**  
( $T_J = 25^\circ\text{C}$ )

Gate current to trigger at $V_D = 12\text{V}$ , mA	$I_{GT}$	150
Gate voltage to trigger at $V_D = 12\text{V}$ , V	$V_{GT}$	3
Non-triggering gate voltage, $T_J = 125^\circ\text{C}$ , and rated $V_{DRM}$ , V	$V_{GDM}$	.25
Peak forward gate current, A	$I_{GTM}$	4
Peak reverse gate voltage, V	$V_{GRM}$	5
Peak gate power, Watts	$P_{GM}$	16
Average gate power, Watts	$P_{G(av)}$	3

**Thermal and Mechanical**

Min., Max. oper. junction temp., $^\circ\text{C}$	$T_J$	-40 to +125
Min., Max. storage temp., $^\circ\text{C}$	$T_{stg}$	-40 to +150
Max. mounting force, lb.		2000 to 2400
Thermal resistance ⑥, double- side cooling, junction to case, $^\circ\text{C}/\text{Watt}$	$R_{\theta JC}$	.045
Case to sink, lubricated, $^\circ\text{C}/\text{Watt}$	$R_{\theta CS}$	.02

- ① Consult recommended mounting procedures.
- ② Applies for zero or negative gate bias.
- ③ Per JEDEC RS-397, 5.2.2.1.
- ④ With recommended gate drive.
- ⑤ Higher  $dv/dt$  ratings available, consult factory.
- ⑥ Per JEDEC standard RS-397, 5.2.2.6.
- ⑦ For operation with antiparallel diode, consult factory.

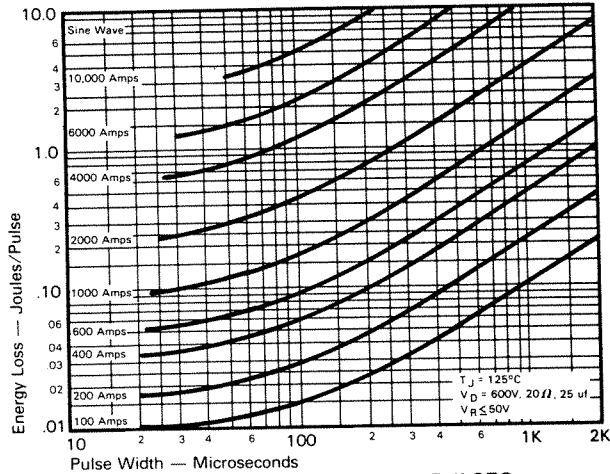


FAST SWITCHING  
THYRISTORS

# Fast Switching SCR T7SH\_45

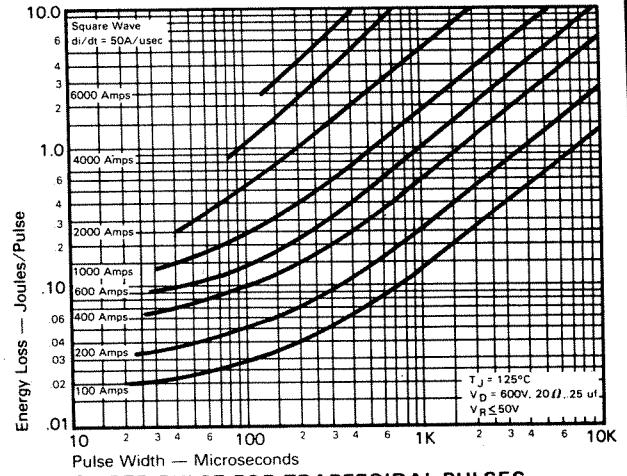
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## Sinusoidal Current Data

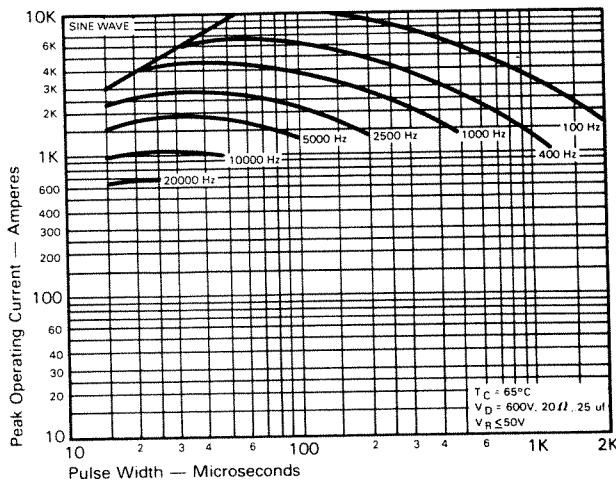


ENERGY PER PULSE FOR SINUSOIDAL PULSES

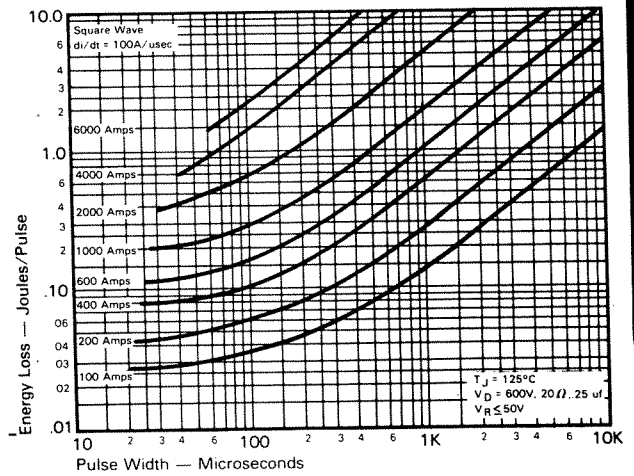
## Trapezoidal Wave Current Data



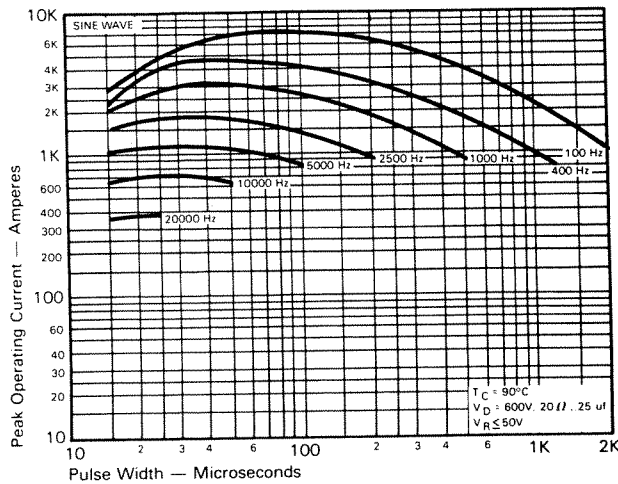
ENERGY PER PULSE FOR TRAPEZOIDAL PULSES  
(di/dt = 50A/usec)



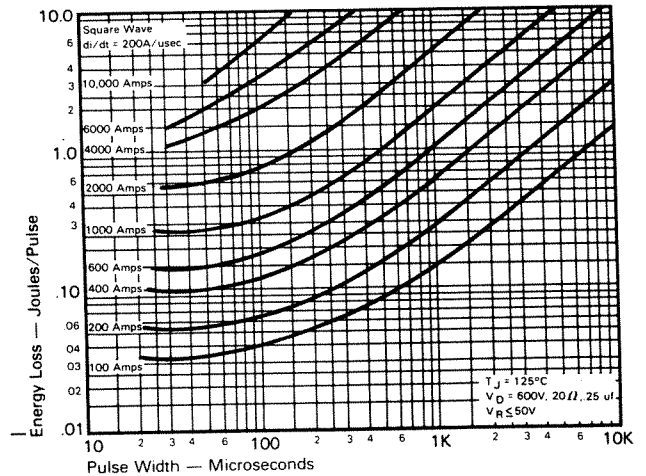
MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT  
vs. PULSE WIDTH ( $T_C = 65^\circ\text{C}$ )



ENERGY PER PULSE FOR TRAPEZOIDAL PULSES  
(di/dt = 100A/usec)



MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT  
vs. PULSE WIDTH ( $T_C = 90^\circ\text{C}$ )



ENERGY PER PULSE FOR TRAPEZOIDAL PULSES  
(di/dt = 200A/usec)

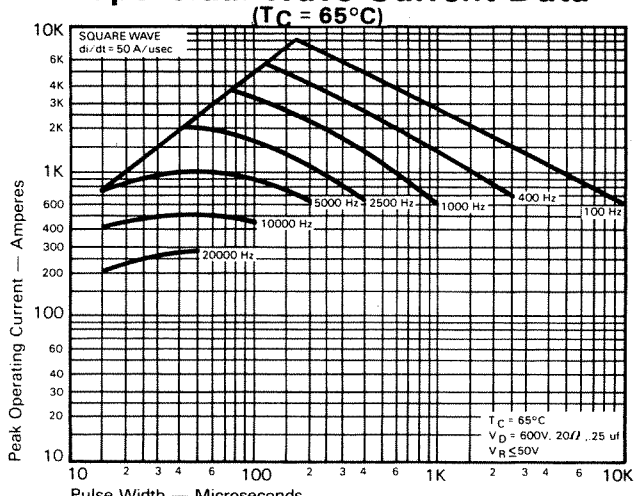
FAST SWITCHING  
THYRISTORS



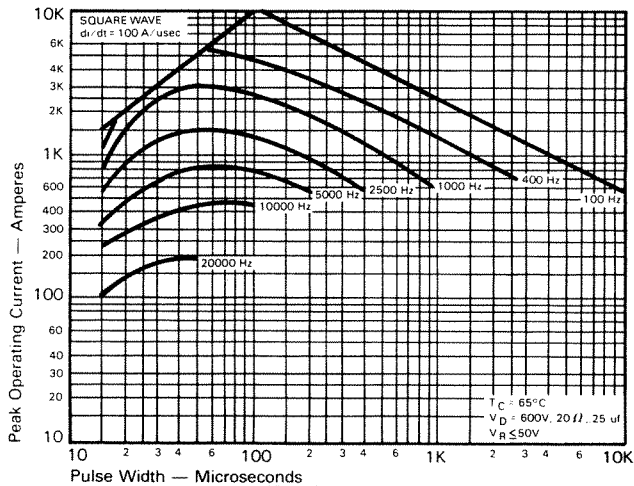
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SCR  
T7SH\_45**

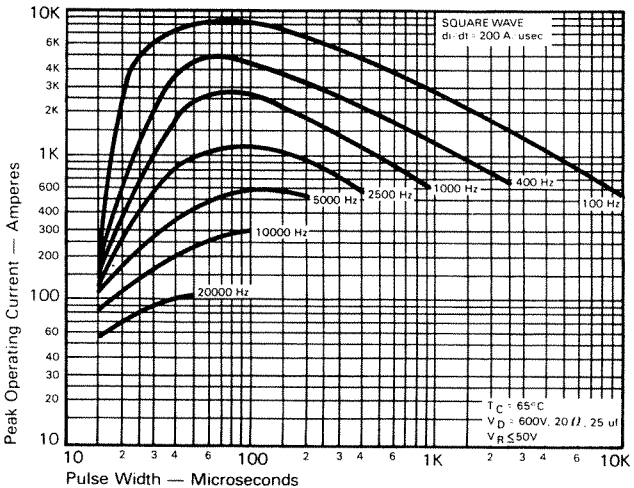
**Trapezoidal Wave Current Data**



**MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT vs. PULSE WIDTH (di/dt = 50A/usec)**

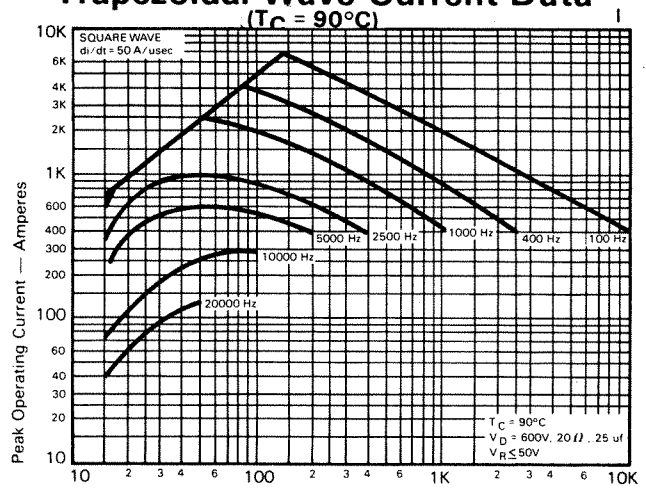


**MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT vs. PULSE WIDTH (di/dt = 100A/usec)**

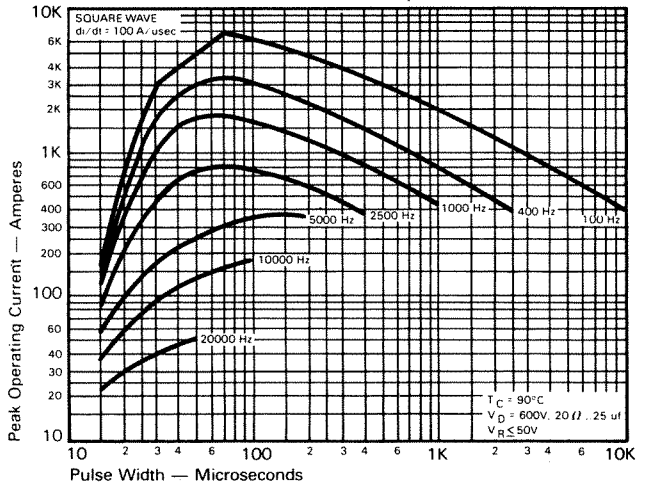


**MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT vs. PULSE WIDTH (di/dt = 200A/usec)**

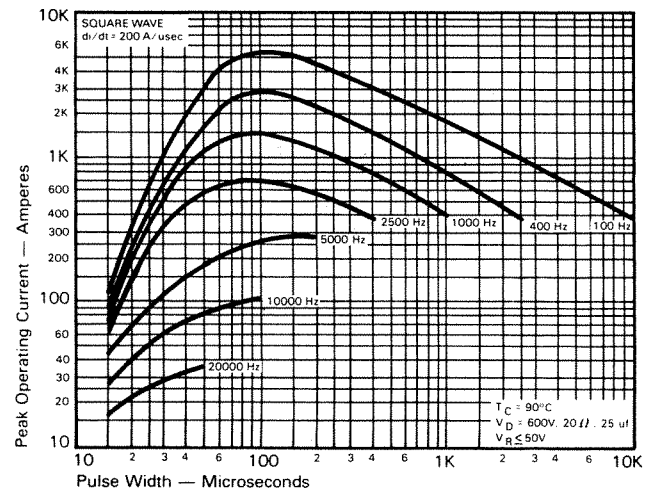
**Trapezoidal Wave Current Data**



**MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT vs. PULSE WIDTH (di/dt = 50A/usec)**



**MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT vs. PULSE WIDTH (di/dt = 100A/usec)**



**MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT vs. PULSE WIDTH (di/dt = 200A/usec)**

FAST SWITCHING THYRISTORS